

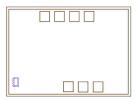
RF Transformer Die

MTX2-73-D+

50Ω 2000 to 7000 MHz

THE BIG DEAL

- Wideband, 2000 to 7000 MHz
- Low insertion loss, 0.6 dB to 6000 MHz
- Low unbalance, 0.8 dB, 4°
- Power handling up to +34 dBm



+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

SEE ORDERING INFORMATION ON THE LAST PAGE

APPLICATIONS

- WLAN
- WiMAX/WIBRO
- ISM
- RADAR

PRODUCT OVERVIEW

Mini-Circuits MTX2-73-D+ is a wideband MMIC balun transformer die with an impedance ratio of 2:1 covering a wide range of applications from 2000 to 7000 MHz. Fabricated using GaAs HBT process technology, this model provides outstanding repeatability with low insertion loss, low amplitude unbalance, low phase unbalance, and RF input power handling up to +34 dBm (2.5W).

KEY FEATURES

Feature	Advantages		
Wideband, 2000 to 7000 MHz	MTX2-73-D+ supports a broad variety of applications including WLAN, WiMAX, WiBRO, ISM, radar and more.		
Low insertion loss	Enables excellent signal power transmission from input to output.		
Low unbalance • 0.8 dB amplitude unbalance • 4° phase unbalance	Low unbalance can improve a system's electromagnetic compatibility by rejecting unwanted common-mode noise.		
Unpackaged Die	Enables the user to integrate the balun directly into hybrids.		

REV. A ECO-009930 MTX2-73-D+ RS/CP/AM 092921





MMIC BALUN RF Transformer Die

MTX2-73-D+

ELECTRICAL SPECIFICATIONS¹ AT 25°C, 50Ω, UNLESS OTHERWISE NOTED.

Parameter	Frequency (MHz)	Min.	Тур.	Max.	Unit	
Impedance Ratio (secondary / primary)			2			
Frequency Range		2000		7000	MHz	
Innertian Laga?	2600-6000		0.6		4D	
Insertion Loss ²	2000-7000		1.9		dB	
A many lists and a 1 limbs allows as	2600-6000		0.5		dB	
Amplitude Unbalance	2000-7000		0.8			
Dhara Habalanas	2600-6000		3		Degree	
Phase Unbalance ³	2000-7000		4			

^{1.} Measured on Mini-Circuits Characterization test board. Die is packaged in 3x3 mm, 12-lead MCL package and soldered on TB-453-MTX273+.

2. Insertion loss is referenced to mid-band loss, 1.5 dB.

3. Relative to 180°

ABSOLUTE MAXIMUM RATINGS

Parameter	Ratings	
Operating Temperature	-40°C to 85°C	
Input RF Power	34 dBm at 25°C	

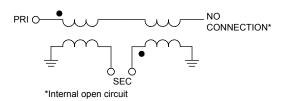
Permanent damage may occur if any of these limits are exceeded.



RF Transformer Die

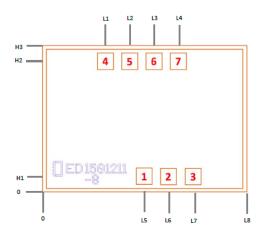
MTX2-73-D+

SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION



Pad Number	Description	
1,3,4,7	Ground	
2	Primary Dot (Unbalanced)	
5	Secondary DOT (Balanced)	
6	Secondary (Balanced)	

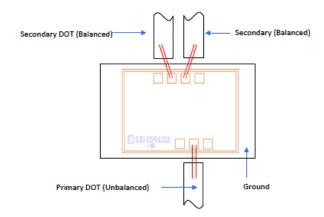
BONDING PAD POSITION



DIE DIMENSIONS IN µm

L1	L2	L3	L4	L5	L6	L7	L8	H1
384	534	684	834	623	773	923	1254	96
H2	НЗ	Thick	ness	Die size			Bond pag to #9 S	
804	900	10	00	1254 x 900			92 x 92	

ASSEMBLY DIAGRAM



ASSEMBLY PROCEDURE

- 1. Storage
 - Dice should be stored in a dry nitrogen purged desiccators or equivalent.
 - ESD
- MMIC GaAs HBT RF Transformer dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be open in clean room conditions at an appropriately grounded anti-static workstation.
- 3. Die Handling and Attachment
 - Devices need careful handling using correctly designed collets, it is recommended to handle the chip along the edges with a custom design collet. The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are Ablestik 84-1 LMISR4 or equivalents. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. The surface of the chip has exposed air bridges and should not be touched with vacuum collet, tweezers or fingers.
- 4. Wire Bonding
 - Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermo-sonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1mil diameter. Bonds must be made from the bond pads on the die to the packaged or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.



RF Transformer Die

MTX2-73-D+

ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD.

ADDITIONAL DETAILED TECHNICAL IN CHINATION IS AVAILABLE ON CON DASH BOARD.					
	Data Table	Data Table			
Performance Data	Swept Graphs	Swept Graphs			
	S-Parameter (S3P Files) Data Set with and with	S-Parameter (S3P Files) Data Set with and without port extension(.zip file)			
Case Style	Die				
Die Ordering and packaging information	Quantity, Package Small, Gel - Pak: 5,10,50,100 KGD* Medium†, Partial wafer: KGD*<1353 Large†, Full Wafer †Available upon request contact sales represe Refer to AN-60-067	Model No. MTX2-73-DG+ MTX2-73-DP+ MTX2-73-DF+			
Environmental Ratings	ENV80	ENV80			

^{*}Known Good Dice ("KGD") means that the dice are taken from PCM good wafer and visually inspected. While this is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

ESD RATING**

Human Body Model (HBM): Class 1B (Pass 500V) in accordance with ANSI/ESD STM 5.1 - 2001

NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained there in. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp
- D. Mini-Circuits does not warrant the accuracy or completeness of the information, text, graphics and other items contained within this document and same are provided as an accommodation and on an As is basis, with all faults.
- E. Purchasers of this part are solely responsible for proper storing, handling, assembly and processing of Known Good Dice (including, without limitation, proper ESD preventative measures, die preparation, die attach, wire bonding and related assembly and test activities), and Mini-Circuits assumes no responsibility therefor or for environmental effects on Known Good Dice.
- F. Mini-Circuits and the Mini-Circuits logo are registered trademarks of Scientific Components Corporation d/b/a Mini-Circuits. All other third-party trademarks are the property of their respective owners. A reference to any third-party trademark does not constitute or imply any endorsement, affiliation, sponsorship, or recommendation by any such third-party of Mini-Circuits or its products.



^{**} Tested in industry standard 3 x 3mm, 12-lead MCLP package

Typical Performance Data

FREQUENCY (MHz)	INSERTION LOSS ⁽¹⁾ (dB)	INPUT RETURN LOSS (dB)	AMPLITUDE UNBALANCE (dB)	PHASE UNBALANCE ⁽²⁾ (deg.)
1500	6.16	2.80	0.76	4.54
1600	5.41	3.38	0.72	4.11
1700	4.77	4.02	0.68	3.70
1800	4.22	4.74	0.65	3.35
1900	3.76	5.53	0.61	2.98
2000	3.37	6.39	0.57	2.66
2100	3.05	7.34	0.53	2.34
2200	2.77	8.38	0.49	1.98
2300	2.55	9.51	0.47	1.69
2400	2.36	10.77	0.44	1.43
2500	2.21	12.11	0.41	1.17
2600	2.09	13.51	0.38	0.94
2700	2.00	14.96	0.35	0.71
2800	1.93	16.24	0.33	0.50
2900	1.87	17.11	0.31	0.36
3000	1.83	17.37	0.29	0.22
3100	1.81	17.04	0.28	0.02
3200	1.79	16.37	0.27	0.14
3300	1.78	15.56	0.25	0.29
3400	1.78	14.76	0.24	0.42
3500	1.77	14.05	0.23	0.53
3600	1.77	13.46	0.23	0.66
3700	1.77	13.02	0.23	0.75
3800	1.77	12.65	0.23	0.83
3900	1.76	12.44	0.24	0.89
4000	1.75	12.32	0.26	0.93
4100	1.73	12.34	0.27	0.97
4200	1.72	12.45	0.28	0.96
4300	1.69	12.68	0.29	0.89
4400	1.67	12.98	0.31	0.81
4500	1.65	13.39	0.33	0.75
4600	1.63	13.86	0.34	0.65
4700	1.61	14.52	0.36	0.47
4800 4900	1.59 1.57	15.21 16.11	0.36 0.37	0.30 0.24
5000	1.57	17.21	0.37	0.24 0.18
5100	1.55	18.52	0.39	0.18
5200	1.54	20.01	0.41	0.08
5300	1.53	21.65	0.42	0.50
5400	1.54	23.09	0.42	0.63
5500	1.56	23.95	0.42	0.65
5600	1.59	23.62	0.43	0.86
5700	1.62	22.45	0.43	0.99
5800	1.66	20.66	0.43	1.10
5900	1.71	19.02	0.44	1.19
6000	1.77	17.48	0.45	1.23
6100	1.83	16.27	0.46	1.25
6200	1.90	15.10	0.48	1.30
6300	1.97	14.18	0.50	1.41
6400	2.05	13.30	0.53	1.47
6500	2.14	12.59	0.56	1.59
6600	2.23	11.89	0.58	1.68
6700	2.33	11.27	0.63	1.76
6800	2.44	10.71	0.67	1.91
6900	2.56	10.21	0.72	2.11
7000	2.68	9.80	0.76	2.30
7100	2.80	9.45	0.81	2.47
7200	2.93	9.13	0.87	2.68
7300	3.06	8.87	0.94	3.01
7400	3.21	8.61	0.99	3.36
7500	3.36	8.38	1.04	3.72

⁽¹⁾ Insertion Loss is referenced to mid-band loss, 1.5 dB

Note: Testdata of Die packaged in 3x3 mm, 12-lead MCL package

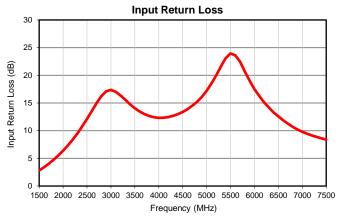


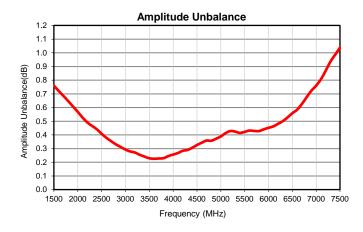


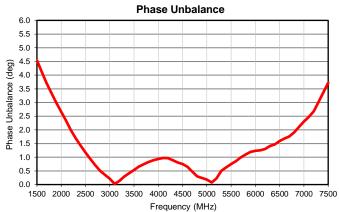
⁽²⁾ Relative to 180°

Typical Performance Data









Note: Testdata of Die packaged in 3x3 mm, 12-lead MCL package









All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-40° to 85° C or -40° to 105° C or -55° to 105° C or -45° to 105° C 105° C Ambient Environment	Refer to Individual Model Data Sheet
Storage Environment (Die)	-65° to 150°C	Individual Model Data Sheet
Storage Environment(Packaging)	-40° to 70°C and 40 to 60% humidity (In Factory Shipped Package)	

ENV80 Rev: C

06/10/24 DCO-1455 File: ENV80.pdf

This document and its contents are the property of Mini-Circuits.